

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOS IV)

TPCP8006

Notebook PC Applications

Portable Equipment Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: $R_{DS(ON)} = 6.5 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 36 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A}$ ($V_{DS} = 20 \text{ V}$)
- Enhancement mode: $V_{th} = 0.5 \text{ to } 1.2 \text{ V}$ ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

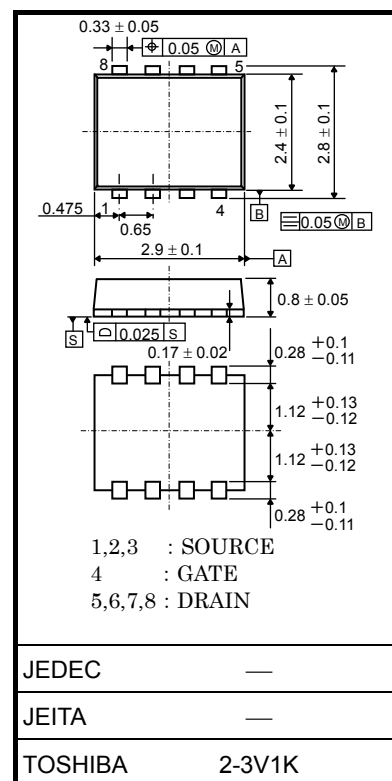
Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	20	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	20	V
Gate-source voltage		V_{GSS}	± 12	V
Drain current	DC (Note 1)	I_D	9.1	A
	Pulse (Note 1)	I_{DP}	36.4	
Drain power dissipation ($t = 5 \text{ s}$) (Note 2a)		P_D	1.68	W
Drain power dissipation ($t = 5 \text{ s}$) (Note 2b)		P_D	0.84	
Single pulse avalanche energy (Note 3)		E_{AS}	21.5	mJ
Avalanche current		I_{AR}	9.1	A
Repetitive avalanche energy (Note 4)		E_{AR}	0.168	mJ
Channel temperature		T_{ch}	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

Note: For Notes 1 to 5, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

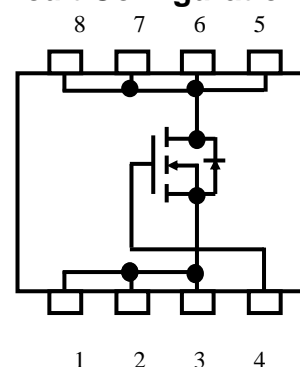
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm

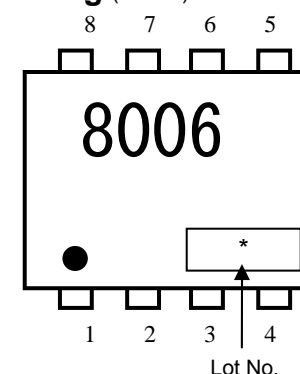


Weight: 0.017g(typ.)

Circuit Configuration



Marking (Note 5)

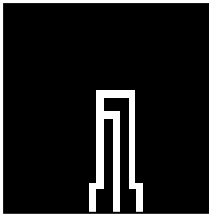


Thermal Characteristics

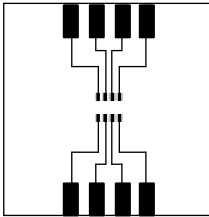
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 5 s) (Note 2a)	$R_{th (ch-a)}$	74.4	°C/W
Thermal resistance, channel to ambient (t = 5 s) (Note 2b)	$R_{th (ch-a)}$	148.8	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



(a)



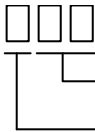
(b)

Note 3: $V_{DD} = 16\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 0.2\text{ mH}$, $R_G = 25\ \Omega$, $I_{AR} = 9.1\text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature.

Note 5: ● on the lower left of the marking indicates Pin 1.

* Weekly code (Three digits):



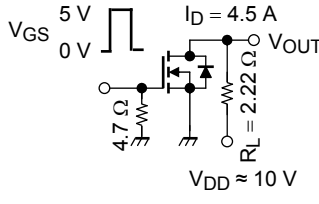
Week of manufacture

(01 for the first week of the year, continuing up to 52 or 53)

Year of manufacture

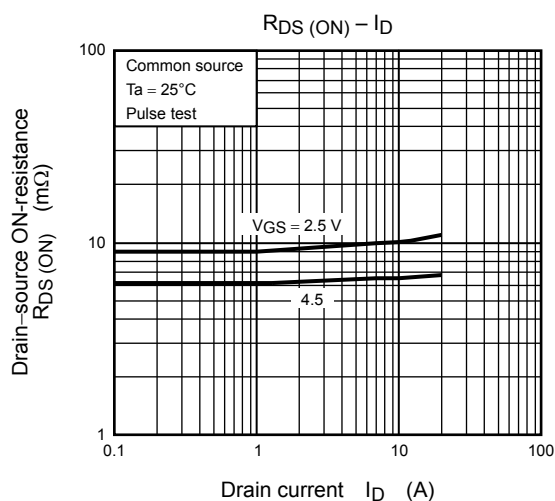
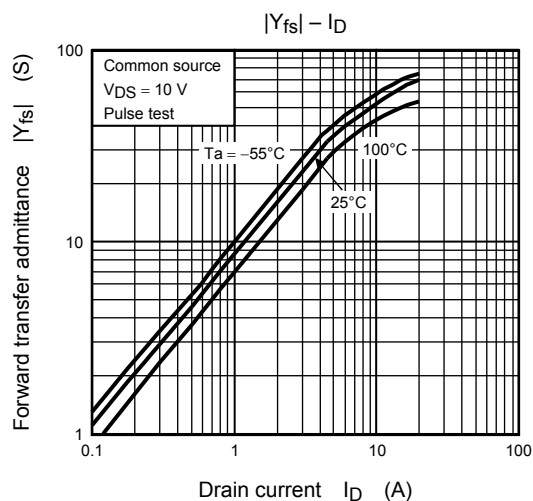
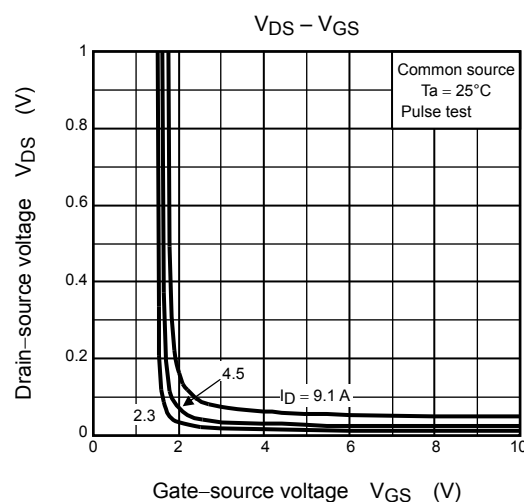
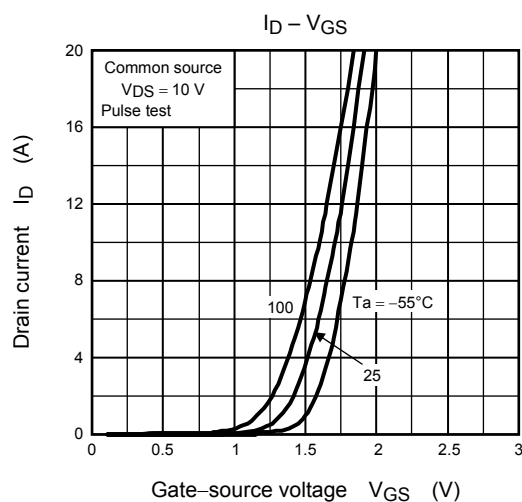
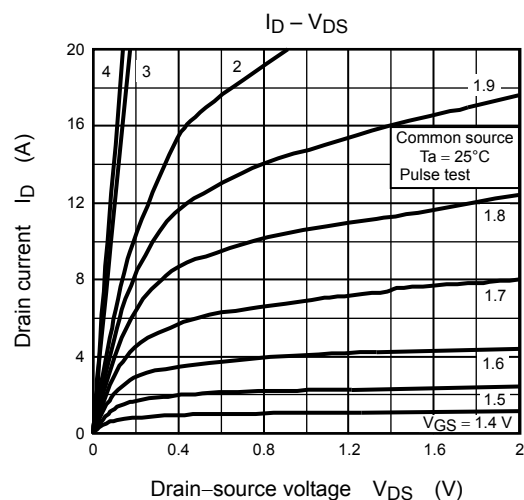
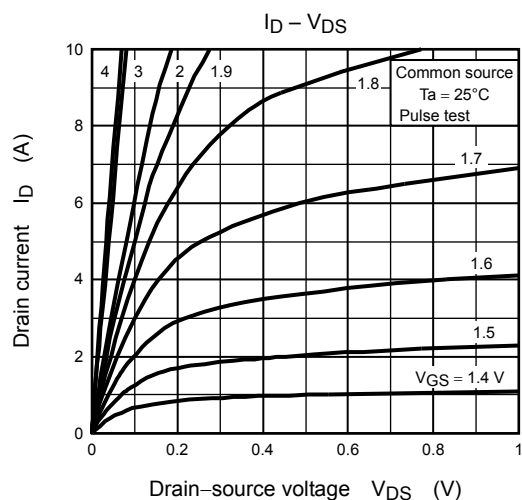
(The last digit of the year)

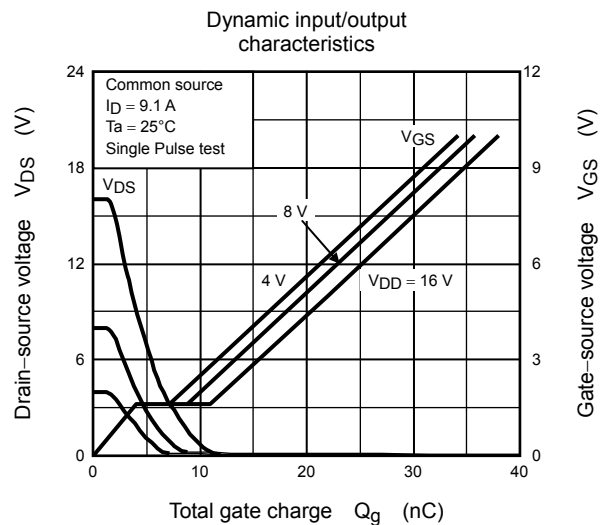
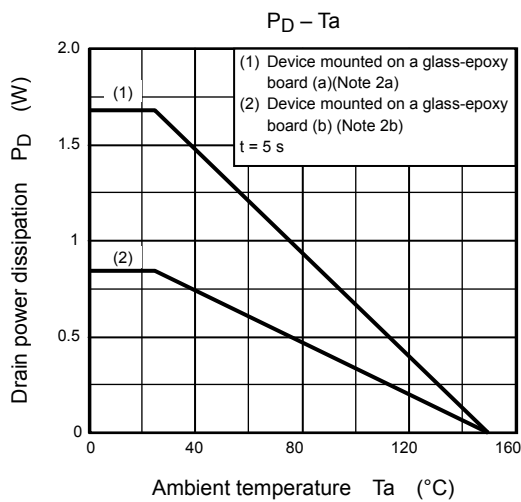
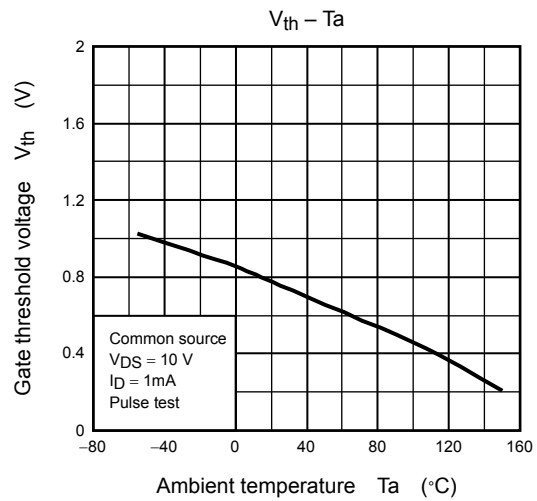
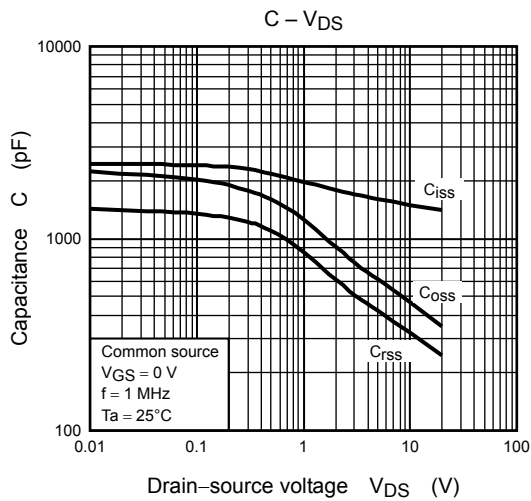
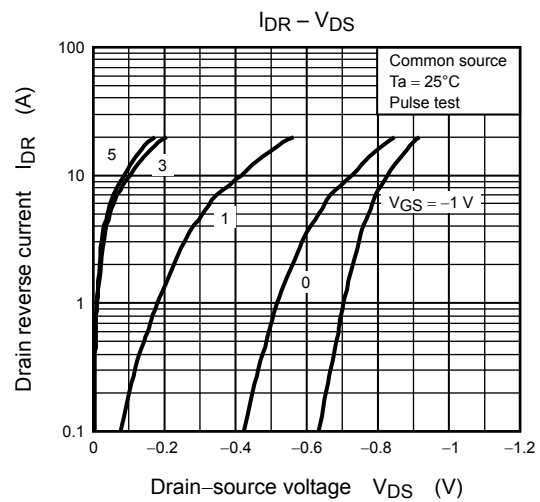
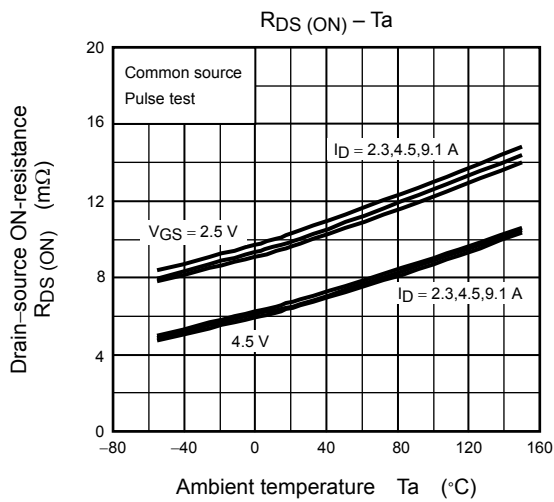
Electrical Characteristics (Ta = 25°C)

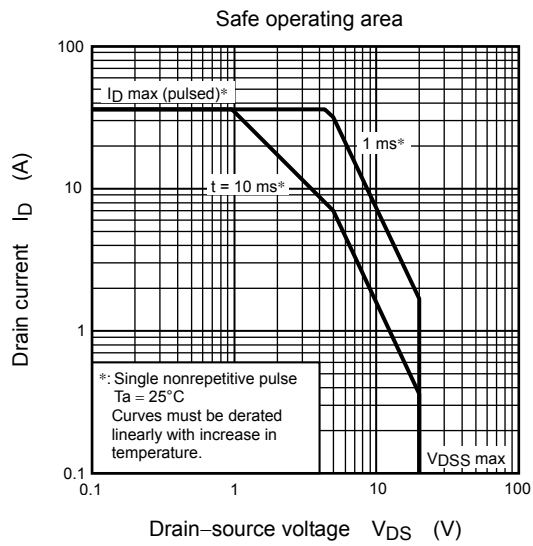
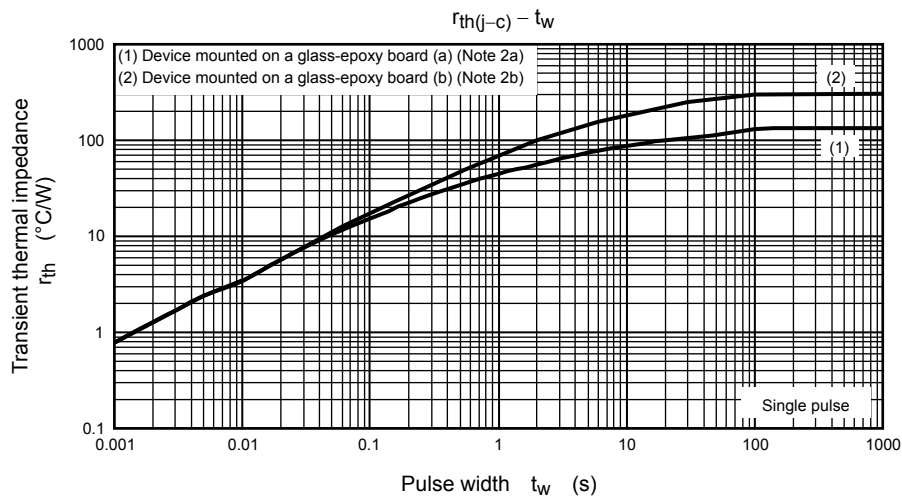
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I _{GSS}	V _{GS} = ±12 V, V _{DS} = 0 V	—	—	±100	μA
Drain cut-off current		I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V	—	—	10	μA
Drain-source breakdown voltage		V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	20	—	—	V
		V _{(BR) DSX}	I _D = 10 mA, V _{GS} = −12 V	8	—	—	
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 1 mA	0.5	—	1.2	V
Drain-source ON-resistance		R _{DS (ON)}	V _{GS} = 2.5 V, I _D = 4.5 A	—	9.5	13.7	mΩ
			V _{GS} = 4.5 V, I _D = 4.5 A	—	6.5	10	
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 4.5 A	18	36	—	S
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	—	1480	—	pF
Reverse transfer capacitance		C _{rss}		—	330	—	
Output capacitance		C _{oss}		—	470	—	
Switching time	Rise time	t _r	 <p>V_{GS} 5 V 0 V I_D = 4.5 A V_{OUT} 47 Ω R_L = 2.22 Ω V_{DD} ≈ 10 V Duty ≤ 1%, t_w = 10 μs</p>	—	8	—	ns
	Turn-on time	t _{on}		—	16	—	
	Fall time	t _f		—	19	—	
	Turn-off time	t _{off}		—	53	—	
Total gate charge (gate-source plus gate-drain)		Q _g	V _{DD} ≈ 16 V, V _{GS} = 5 V, I _D = 9.1 A	—	22	—	nC
Gate-source charge 1		Q _{gs1}		—	4	—	
Gate-drain (“Miller”) charge		Q _{gd}		—	7	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse (Note 1)	I_{DRP}	—	—	—	36.4	A
Forward voltage (diode)		V_{DSF}	$I_{DR} = 9.1 \text{ A}, V_{GS} = 0 \text{ V}$	—	—	-1.2	V







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